

P. P. SAVANI UNIVERSITY

Fifth Semester of B.Sc. Examination

December-2021

SSCH3190–Applied Chemistry- Nanomaterials

14.12.2021, Tuesday Time: 12:30 p.m. to 03:00 p.m. Maximum Marks: 60

Instructions:

1. The question paper comprises of two sections.
2. Section I and II must be attempted in separate answer sheets.
3. Make suitable assumptions and draw neat figures wherever required.
4. Use of scientific calculator is allowed.

Section-I (Total Marks - 30)

Q.1 Short Questions [10]

1.1 Objectives [05]

1.1a Properties of sol-gel method

- A producing small particles in material chemistry
- B mostly used for the synthesis of metal oxides
- C initial step of this process is converting monomers into a sol
- D All of the above are correct

1.1b k_g stands for_____?

- A rate constant for inter -micellar exchange dynamics
- B rate constant for nucleation
- C rate constant for particle growth
- D rate constant for chemical reaction

1.1c Emulsions are divided according to the _____?

- A size of droplet
- B Weight of droplet
- C Volume of the droplet
- D None of the above are correct

1.1d Fullerenes are_____?

- A nanostructure
- B Nanotubes
- C Nano tools
- D All of the above are correct

1.1e In which synthesis method, Chemical reactions occur on the growth surface

- A CVD
- B Sol-gel method
- C High ball milling
- D Polyol method

1.1f What solvent is used in polyol method?

- A Oil

- B Water
- C Ethylene glycol
- D Acetone

1.1g The optical properties of nanostructured semiconductors are highly

- A size dependent
- B Mass dependent
- C Volume dependent
- D Weight dependent

1.1h Name the material, which has mechanical tensile strength can be 400 times that of steel?

- A CNT
- B QD
- C Composite
- D Semiconductor

1.1i A nanowire is a wire of dimensions of the order of

- A nanometer
- B Micrometer
- C Centimeter
- D Meter

1.1j What is the wavelength of blue light producing quantum dots?

- A 450
- B 550
- C 650
- D 750

1.2 **Answer the Following: (MCQ/Short Question/Fill in the Blanks)** [05]

- 1.2a Full form of SWCNT & QD?
- 1.2b Write down name of two Nano tool techniques?
- 1.2c Define the term quantum wire?
- 1.2d CNTs are chemically bonded with _____ bonds?
- 1.2e What are the fundamentals steps of PVD method?

Q.2 **Short Notes (Attempt any two)** [06]

- A Write the synthesis method of nanomaterials using sol-gel method?
- B Describe the quantum dots?
- C Write the synthesis method of nanomaterials using the Polyol method?

Q.3 **Explain in detail (Attempt any two)** [14]

- A Discuss about the 1-d, 2-d and 3-d nanomaterials?
- B Write the PVD method and high energy ball milling method for synthesis of nanomaterials?
- C Discuss about the composite material?

Section-II (Total Marks - 30)

Q.1 Short Questions

[10]

1.1 Objectives

[05]

1.1a What is NGEV

- A Next-generation electric vehicles
- B Nano-generation electric vehicles
- C New-generation electric vehicles
- D None of the above

1.1b For making high definition TV which material is used

- A Phosphors
- B Silicone
- C Aluminium
- D Zirconium

1.1c In Intrinsic Semiconductor the Number of Conduction electrons will be _____ the Number of Vacant sites

- A Equal to
- B Greater than
- C Lower than
- D All of the above

1.1d _____ & _____ are elemental semiconductors

- A Si, Ge
- B Ti, Mn
- C W, Sc
- D Cd, Zn

1.1e What is CDDSs

- A controlled drug delivery systems
- B carrier drug delivery systems
- C Capacity drug delivery systems
- D None of the above are correct

1.1f Semiconductors have conductivities in the range

- A 10^{-4} to 10^{+4} S/m
- B 10^{-1} to 10^{+4} S/m
- C 10^{-4} to 10^{+5} S/m
- D 10^{-8} to 10^{+9} S/m

1.1g Factors which makes porous silicone as unique material

- A its ordered porous structure
- B its tunable particle size
- C its large pore volume and surface area
- D All of the above are correct

- 1.1h What is full form of RFID
- A Radio Frequency Identification Devices
 - B Organic Light Emitting Diodes
 - C Resonance frequency Identification Devices
 - D None of the above are correct

- 1.1i _____ are used in organic Light Emitting Diodes
- A Semiconductors
 - B Conductors
 - C Metal Oxides
 - D All of the above

- 1.1j In N-type semiconductors,
- A pentavalent element is added to the intrinsic semiconductor
 - B tetravalent element is added to the intrinsic semiconductor
 - C trivalent element is added to the intrinsic semiconductor
 - D None of the above

1.2 Answer the Following: (MCQ/Short Question/Fill in the Blanks) [05]

- 1.2a What is surface plasmon resonance?
- 1.2b Write the name of two typical engineered composite materials?
- 1.2c A fullerene is an allotrope of _____?
- 1.2d What is N-type semiconductor?
- 1.2e What is Extrinsic semiconductors?

Q.2 Short Notes (Attempt any two) [06]

- A Write a short note on N-type semiconductors with diagram?
- B Give a short note on application of nanomaterials in making towards Better Insulation Materials?
- C Describe the Hall effect with diagrams?

Q.3 Explain in detail (Attempt any two) [14]

- A Discuss about Nanowires?
- B What are semiconductors? How many types of semiconductors are there? Draw the schematic diagram of Intrinsic semiconductors?
- C Write a long note on the World of Metal Oxide Nanoparticles?